

Ordering number : ENN6961

MOSFET : P-Channel Silicon MOSFET
SBD : Schottky Barrier Diode

SANYO

MCH5802

DC / DC Converter Applications

Features

- Composite type with a P-Channel Silicon MOSFET (MCH3308) and a Schottky Barrier Diode (SBS006M) contained in one package facilitating high-density mounting.

[MOSFET]

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

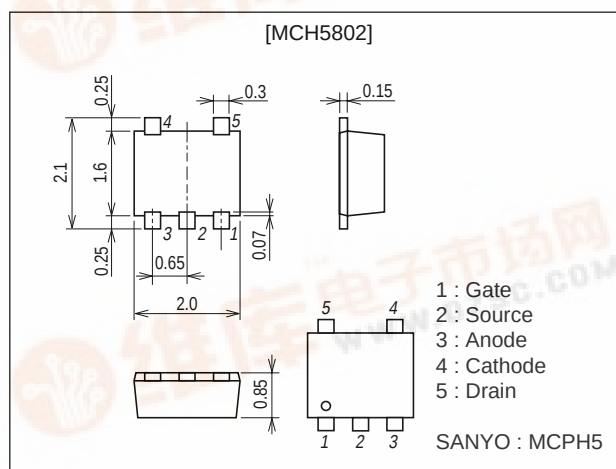
[SBD]

- Short reverse recovery time.
- Low forward voltage.

Package Dimensions

unit : mm

2195



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
[MOSFET]				
Drain-to-Source Voltage	V_{DS}		-30	V
Gate-to-Source Voltage	V_{GS}		± 20	V
Drain Current (DC)	I_D		-1	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-4	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (900mm ² X 0.8mm) 1unit	0.8	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +125	°C
[SBD]				
Repetitive Peak Reverse Voltage	V_{RRM}		30	V
Nonrepetitive Peak Reverse Surge Voltage	V_{RSM}		30	V
Average Output Current	I_O		0.5	A
Surge Forward Current	I_{FSM}	50Hz sine wave, 1 cycle	10	A
Junction Temperature	T_j		-55 to +125	°C
Storage Temperature	T_{stg}		-55 to +125	°C

Marking : QB

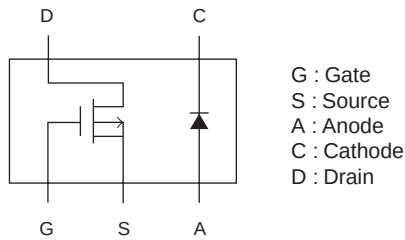
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Electrical Characteristics at Ta=25°C

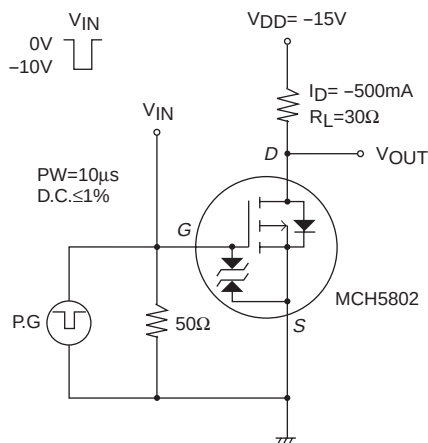
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[MOSFET]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-30V, VGS=0			-1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-500mA	570	820		mS
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-500mA, VGS=-10V		430	560	mΩ
	RDS(on)2	ID=-300mA, VGS=-4V		780	1090	mΩ
Input Capacitance	Ciss	VDS=-10V, f=1MHz		80		pF
Output Capacitance	Coss	VDS=-10V, f=1MHz		15		pF
Reverse Transfer Capacitance	Crss	VDS=-10V, f=1MHz		13		pF
Turn-ON Delay Time	tD(on)	See specified Test Circuit		7		ns
Rise Time	tR	See specified Test Circuit		20		ns
Turn-OFF Delay Time	tD(off)	See specified Test Circuit		15		ns
Fall Time	tF	See specified Test Circuit		7		ns
Total Gate Charge	QG	VDS=-10V, VGS=-10V, ID=-1A		2.6		nC
Gate-to-Source Charge	QGS	VDS=-10V, VGS=-10V, ID=-1A		0.5		nC
Gate-to-Drain "Miller" Charge	QGd	VDS=-10V, VGS=-10V, ID=-1A		0.6		nC
Diode Forward Voltage	VSD	IS=-1A, VGS=0		-0.9	-1.5	V
[SBD]						
Reverse Voltage	VR	IR=0.5mA	30			V
Forward Voltage	VF1	IF=0.3A		0.35	0.40	V
	VF2	IF=0.5A		0.42	0.47	V
Reverse Current	IR	VR=10V			200	μA
Interterminal Capacitance	C	VR=10V, f=1MHz		20		pF
Reverse Recovery Time	tRR	IF=IR=100mA, See specified Test Circuit.			10	ns

Electrical Connection (Top view)



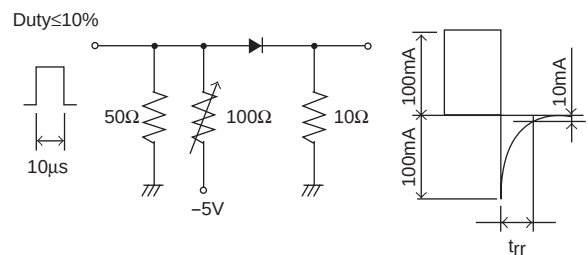
Switching Time Test Circuit

[MOSFET]

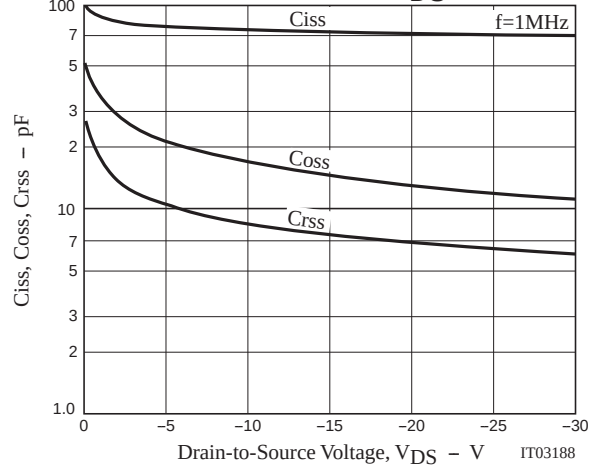
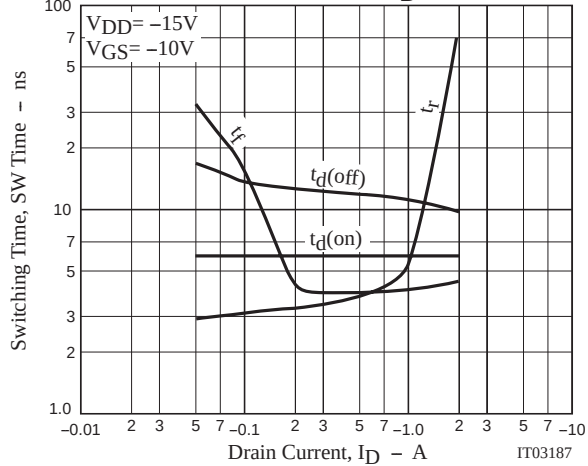
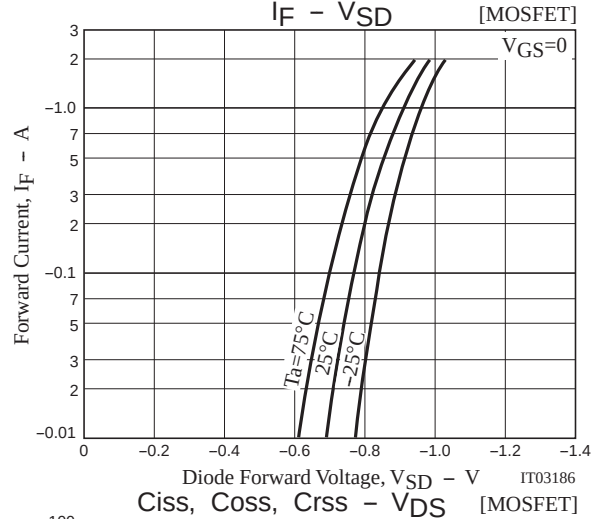
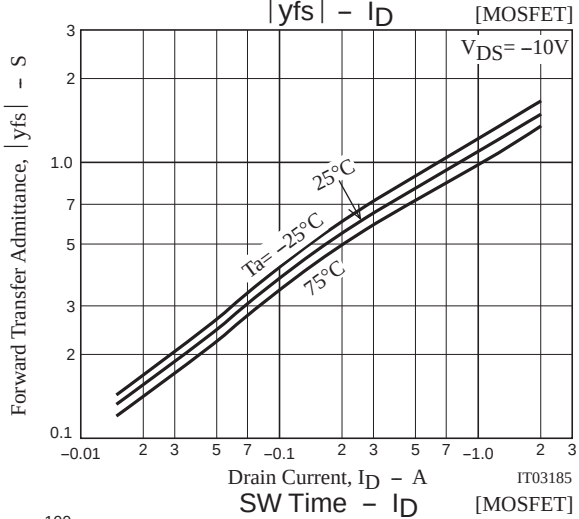
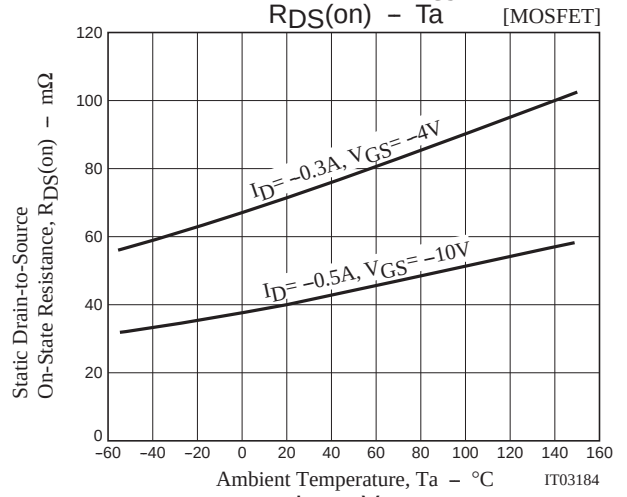
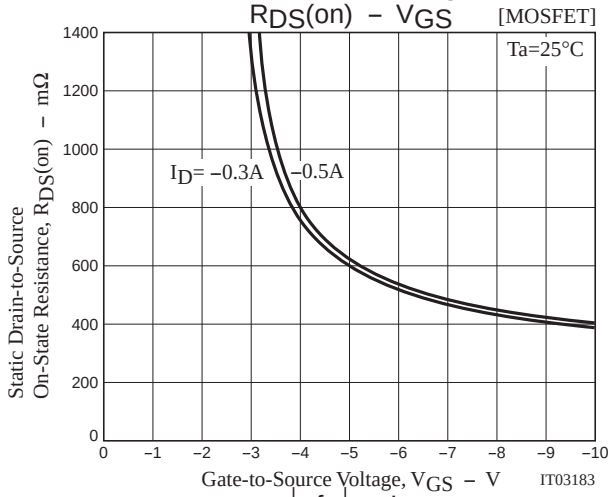
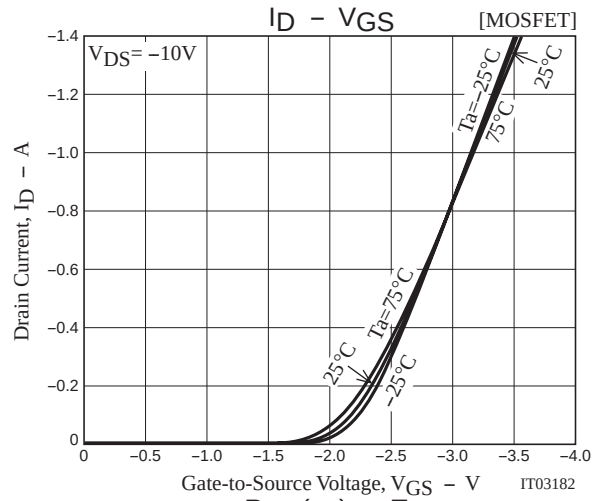
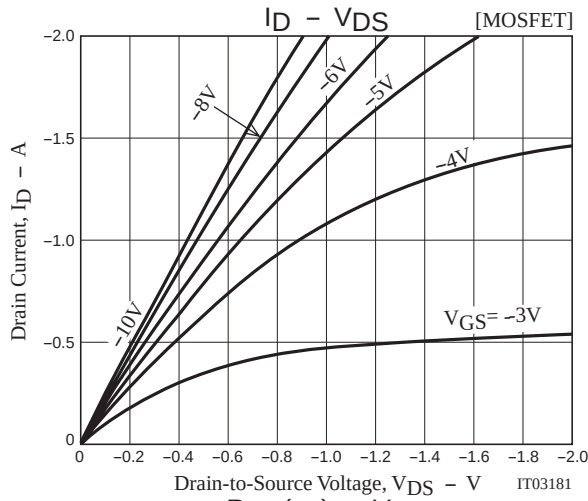


t_{rr} Test Circuit

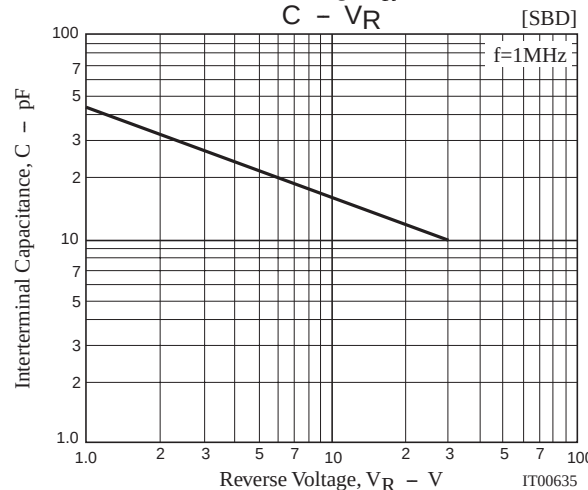
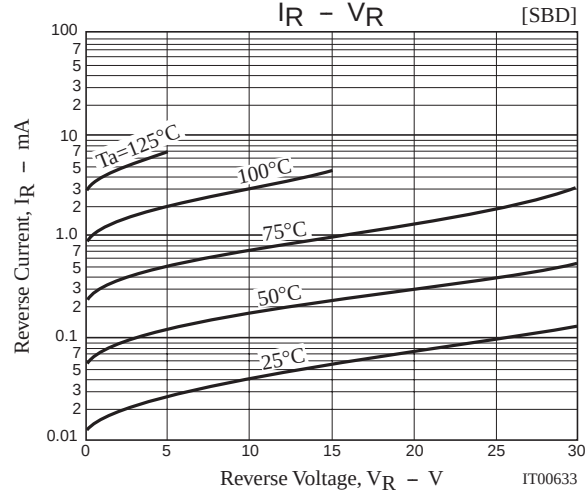
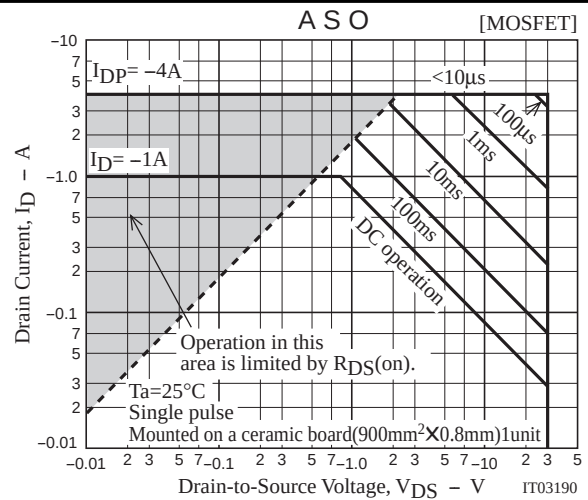
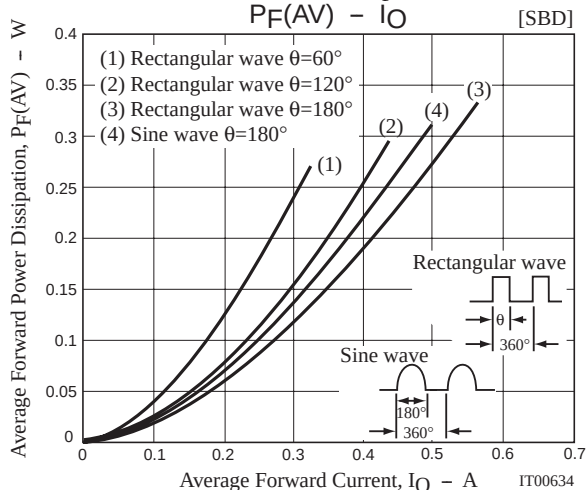
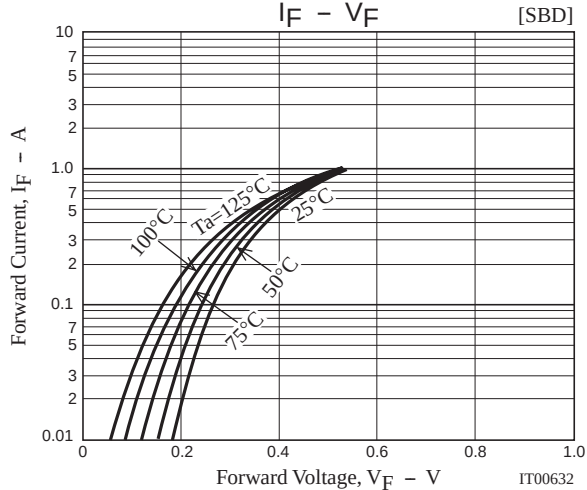
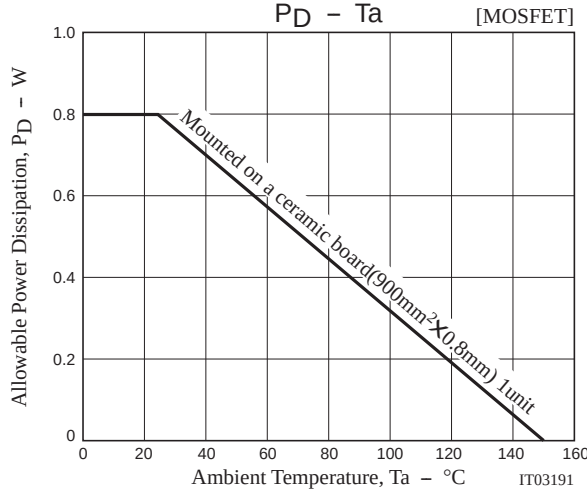
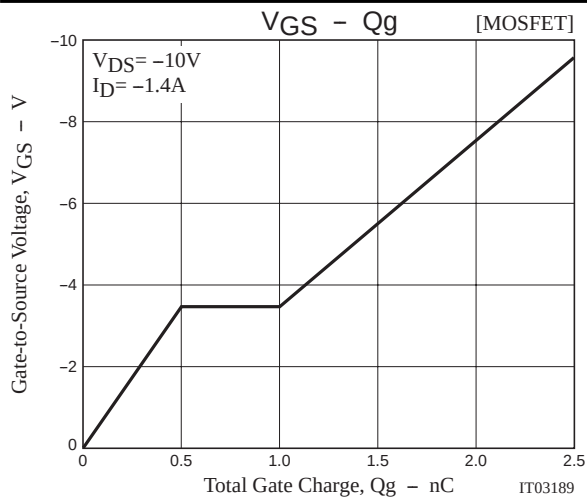
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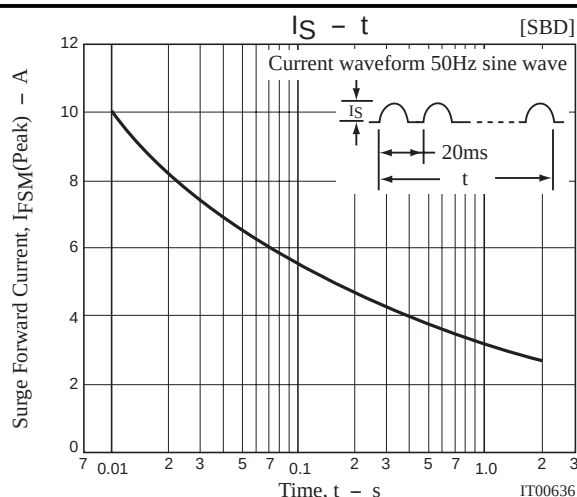
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